Lecture Outline: Atomic Structure

- Electronic Structure of the Atom
- Periodic Table
- Types of Atomic Bonding, primary/secondary bonds
- Coordination and next neighbors
- Binding Energy, Interatomic Spacing, & their dependence on temperature
- Properties from Bonding
- Summary Bonding/Properties of Material Classes

Bohr's Atom model



Nucleus: Z = # protons

= 1 for hydrogen to 94 for plutonium N = # neutrons

Atomic mass $A \sim Z + N$,

since nucleons are about 1840 times heavier than electrons

Quantum mechanics delivers better model

- $\Box \text{ Schrödinger equation time } -\frac{\hbar^2}{2m}(\frac{\partial^2\Psi}{\partial x^2} + \frac{\partial^2\Psi}{\partial y^2} + \frac{\partial^2\Psi}{\partial z^2}) + U\Psi = i\hbar\frac{\partial\Psi}{\partial t}$ dependent
- $\Box \text{ In atom stationary } \Psi(x, y, z, t)^2 \text{ Probability density states, time independent Schrödinger equation} \qquad \frac{\partial^2 \mathbf{y}}{\partial x^2} + \frac{\partial^2 \mathbf{y}}{\partial y^2} + \frac{\partial^2 \mathbf{y}}{\partial z^2} + \frac{\partial^2 \mathbf{y}}{\partial z^2}$
- Solving this equation for Coulomb potential

$$\mathbf{y}(x, y, z)^2$$
 Probability density
 $U = -\frac{e^2}{4\mathbf{p}\mathbf{e}_0 r}$

Eigenvalues are discrete energy levels for electron

Square of eigenfunction gives probability density (where electron can be found)

There are 3 quantum numbers, n, *I*, m₁

 $n = 1, 2, 3, \ldots$

l = 0, 1, 2, n-1

 $m_l = 0, 1, 2, \pm l$

 $H\mathbf{y}_n = E_n\mathbf{y}_n$ $E_{n} = -\frac{me^{4}}{32\boldsymbol{p}^{2}\boldsymbol{e}_{0}^{2}\hbar^{2}}(\frac{1}{n^{2}})$ $\mathbf{y}_{1,0,0} = \frac{1}{\sqrt{\mathbf{p}} a_0^{3/2}} e^{-r/a_0}$

n and *l* have special importance for orbitals, so a complementary nomenclature is used

There is one more quantum number: $m_s = \pm \frac{1}{2}$ called "spin up" or "spin down"



The atomic structure of sodium, atomic number 11, showing the electrons in the *K*, *L*, and *M* quantum shells

Pauli's exclusion principle:

if in the same system, no two electron can have the same set of quantum numbers; consequence in each of Schrödinger's orbitals, we have a maximum of two electrons, one "spin up" the other "spin down" in each orbital

TABLE 2-2 The pattern used to assign electrons to energy levels								
	i = 0 (s)	i = 1 (p)	i = 2 (d)	i = 3 (f)	i = 4 (g)	/ = 5 (約)		
n = 1 (K)	2							
n = 2 (L)	2	6						
n = 3 (M)	2	6	10					
n = 4 (N)	2	6	10	14				
n = 5(0)	2	6	10	14	18			
n = 6 (P)	2	6	10	14	18	22		

Note: 2, 6, 10, 14, ... refer to the number of electrons in the energy level.

The complete set of quantum numbers for each of the 11 electrons in sodium

ELECTRON ENERGY STATES

Electrons tend to occupy lowest available energy state



STABLE ELECTRON CONFIGURATIONS

- have complete s and p subshells
- tend to be unreactive, inert gasses
- Z Element Configuration
- 2 He 1s²
- 10 Ne 1s²2s²2p⁶
- 18 Ar 1s²2s²2p⁶3s²3p⁶
- $36 \quad \text{Kr} \quad 1s^2 2s^2 2p^6 3s^2 3p^6 3d^{10} 4s^2 4p^6$

SURVEY OF ELEMENTS

• Most elements: Electron configuration not stable.

<u>Element</u>	Atomic #	Electron configuration
Hydrogen	1	1s ¹
Helium	2	1s ² (stable)
Lithium	3	1s ² 2s ¹
Beryllium	4	1s ² 2s ²
Boron	5	1s ² 2s ² 2p ¹
Carbon	6	1s ² 2s ² 2p ²
Neon	10	1s ² 2s ² 2p ⁶ (stable)
Sodium	11	1s ² 2s ² 2p ⁶ 3s ¹
Magnesium	12	1s ² 2s ² 2p ⁶ 3s ²
Aluminum	13	1s ² 2s ² 2p ⁶ 3s ² 3p ¹
		•••
Argon	18	<u>1s²2s²2p⁶3s²3p⁶ (stable)</u>
•••	•••	
Krypton	36	1s ² 2s ² 2p ⁶ 3s ² 3p ⁶ 3d ¹⁰ 4s ² 4 ⁶ (stable)

• Why? Valence (outer) shell usually not filled completely.

THE PERIODIC TABLE



Electropositive elements: Readily give up electrons to become + ions. Electronegative elements: Readily acquire electrons to become - ions.

Comments Periodic Table

- □ III-V semiconductor is a semiconductor that is based on group IIIA and VA elements (e.g. GaAs).
- □ II-VI semiconductor is a semiconductor that is based on group IIB and VIA elements (e.g. CdSe).
- Transition elements are the elements whose electronic configurations are such that their inner "d" and "f" levels begin to fill up.
- Electropositive element is an element whose atoms want to participate in chemical interactions by donating electrons and are therefore highly reactive.
- Electronegative element is an element whose atoms want to participate in chemical interactions by accepting electrons and are therefore also highly reactive.

Electronegativity: relative measure of ability of an atom to attract electrons to form an anion, in HCI CI is more electronegative than H and, therefore, attracts the electron more

ELECTRONEGATIVITY

- Ranges from 0.7 to 4.0,
 - Large values: tendency to acquire electrons.

İÅ																	0
Н 2.1	ILA											UIA	IVA	YA	VIA	VIIA	He -
Li 1.0	Be 1.5											5 8 2.0	6 C 2.5	7 N 3.0	8 Ó 9.5	F 4.0	Ne -
Na 0.9	Mg 1.2	INB	NB	VB	VIB-	VIIB	·	<u>v</u> !		18	IIB	13 Ai 1.5	14 Si 1.6	25 P 2.1	16 \$ 2.5	CI 3.0	Ar -
K 0.8	Ca 1.0	23 Sc 1.5	Ti 1.5	23 V 1.6	Cr 1.6	25 Ma 1,5	Fe 1.8	27 Co 18	Ni 1.8	29 Cu 1.9	Zn 1.8	31 Ga 1.6	32 Ge 1.6	As 2.0	94 Se 2.4	Br 2.8	Kr -
Rb 0.8	Sr 1.0	90 Y 1.2	40 2r 1.4	41 Nb 1.6	42 Mo- 1.8	43 Te 1.9	44 Re 2.2	45 Rh 22	46. Pd 2.2	47 Ag 1.9	48 Cd 1.7	49 in 1.7	50 Sn 1.8	51 55 1.9	52 Re 2.1	ï 2.5	Xe -
Cs 0.7	Ba 0.9	57-71 La-Le L1-L2	72 H1 1.9	73 Ta 1.5	74 W	75 Re 1.9	76 0s 2.2	77 ir 22	78 Pt 2.2	70 Au 2.4	80 Hg 1.9	81 П 1.2	82 Pb 1.6	81 81 1.0	84 Po- 2.0	At 2.2	Rn -
Fr 0.7	Ra 0.9	89-102 Ac-No 1.1-1.7								73111 (meaning)	•						
81		6.															

Smaller electronegativity

Larger electronegativity



The electronegativities of selected elements relative to the position of the elements in the periodic table

Atomic Bonding

 4 basic types: Metallic bond, Covalent bond, Ionic bond, van der Waals bond
first 3 are primary bonds ^{eV}/_{atom}, real compounds frequently have a mixture of these basic types

Secondary bonds/Van der Waals bonds: < 0.1 $^{\rm eV}/_{\rm atom}$, due to dipol-dipol interactions between atoms or molecules

Several physical properties can be explained on the basis of atomic bonds. As covalent bonds are highly directional, we will have large anisotropy for such crystals

e.g. Ductility refers to the ability of materials to be stretched or bent without breaking, we have it mainly for metals because metal bonds are both non-directional and non-polar

Coordination of atoms, nearest neighbors, next nearest neighbors determine many physical properties as well

Coordination of atoms, molecules, nearest neighbors

Atoms or ions are modeled as hard spheres that cannot penetrate each other, two (or many) of them come together to form a molecule (or crystal)

Geometry of 3D atomic arrangement then determines the number of nearest neighbors, **coordination number**

For different kinds of bonds and different compounds and crystals, we have different bond lengths. This is accounted for by sets of different radii of hard spheres that represent ionic, covalent and metallic bonds.

A **primary bond crystal**, however large, may be considered to be one large molecule,



FIGURE 2.6 Relative sizes of some atoms and ions. Values are given in nanometers for the radii of the atoms and ions. Metallic radii are given for atoms where applicable. (*Adapted from F. M. Miller, "Chemistry: Structure and Dynamics," McGraw-Hill, 1984, p. 176.*)



A two-dimensional crystal of pennies and quarters

Fig. 1.35: Packing of coins on a table top to build a two dimensional crystal.

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Figure 2-11 The largest number of ions of radius R that can coordinate an atom of radius r is 3 when the radius ratio, r/R = 0.2. (Note: The instability for CN = 4 can be reduced but not eliminated by allowing a three-dimensional, rather than a coplanar, stacking of the larger ions.)



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IONIC BONDING

- Occurs between + and ions.
- Requires electron transfer.
- Large difference in electronegativity required.
- Example: NaCl



In a bit more detail, also a crystal is formed easily



An ionic bond is created between two unlike atoms with very different electronegativities. When sodium donates its valence electron to chlorine, each becomes an ion; Coulomb attraction occurs, and the ionic bond is formed $\vec{F} = \frac{|Z_1 Z_2|e^2}{4\pi e^2 r^2}$

As bond is non directional, coordination in crystal is high, 3D arrangements are determined by geometry



This crystal consist of Na⁺ and Cl⁻ ions, not NaCl molecules, so it may be considered to be one large molecule itself

Fig. 1.9: (a) A schematic illustration of a cross section from solid NaCl. NaCl solid is made of $Cl - and Na^+$ ions arranged alternatingly so that the oppositely charged ions are closest to each other and attract each other. There are also repulsive forces between the like-ions. In equilibrium the net force acting on any ion is zero. (b) Solid NaCl.



When voltage is applied to an ionic material, entire ions must move to cause a current to flow. Ion movement is slow and the electrical conductivity is, therefore, poor.

EXAMPLES: IONIC BONDING

• Predominant bonding in Ceramics







COVALENT BONDING

- Requires shared electrons
- Example: CH4
 - C: has 4 valence e, needs 4 more
 - H: has 1 valence e, needs 1 more

Electronegativities are comparable, so electrons are shared. shared electrons from hydrogen atoms

shared electrons

from carbon atom

Quantum mechanics prescribes directionality of the orbitals, covalent bonds, must, therefore, be highly directional, physical properties must be highly anisotrope

CH₄

С



Covalent bonding requires that electrons be shared between atoms in such a way that each atom has its outer *sp* orbital filled. In silicon, with a valence of four, four covalent bonds must be formed

coordination in covalently bound crystals tends to be low



Fig. 1.6: The diamond crystal is a covalently bonded network of carbon atoms. Each carbon atom is bonded covalently to four neighbors forming a regular three dimensional pattern of atoms which constitutes the diamond crystal.

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Figure 2-17 The SiO_4^{4-} tetrahedron represented as a cluster of ions. In fact, the Si—O bond exhibits both ionic and covalent character.

Covalent bonds are directional! In crystalline silicon, perfect tetrahedra are formed, with angles of 109.5° between each covalent bond. If crystalline, we can only have a perfect tetrahedron for atoms with exactly the same electronegativity, i.e. Si atoms.

In SiO₂ glass, SiO₄ tetrahera can be "close to perfect" as long range order is missing, in fact that bond is partly ionic / partly covalent



Molecules of nonmetals, Molecules containing metals & nonmetals,

Elemental solids (right half side of Periodic Table)

Compound solids (about column IV A), semiconductors, GaAs

METALLIC BONDING



metallic bond forms when atoms give up their valence electrons, 1, 2 or 3 from each atom, which then form an electron sea. The positively charged atom cores are bonded by mutual attraction to the negatively charged electrons. As the bond is not polar, metals are ductile

• Primary bond for metals and their alloys,

there are exceptions, the intermetallics

As bond is nondirectional, coordination in a crystal

is high



Fig. 1.7: In metallic bonding the valence electrons from the metal atoms form a "cloud of electrons" which fills the space between the metal ions and "glues" the ions together through the coulombic attraction between the electron gas and positive metal ions.

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When voltage is applied to a metal, the electrons in the electron sea can easily move and carry a current, if there are different metal atoms in between, i.e. point defects, or other crystal defects, the current is impeded, so conductivity will be high but strongly depended of perfection of crystal

	1																		10
	1A 1 1.01	1																	2 4.00
1	H			Atomic	number —	- 12 (00 0)	Ate	omic mass (mean relativ										He
	-259 0.09 -253 2.1	2 2A	Ele	ctron config	uration —	[43 (98.9] [Kr] 4d ⁵ 5s ² 7	-Ox	idation state	es					13 3B	14 4B	15 5B	16 6B	17 7B	- 0.18 -269 -
	3 6.94 [He] 2s	4 9.01 [He] 2s ²		Melting po	int [°C]	Tc	Na De	me nsity [g/cm]	3], for gases					5 10.81 [He] 2s ² 2p	6 12.01 (He) 2s ² 2p ²	7 14.01 [He] 2s ² 2p ³	8 16.00 [He] 2s ² 2p ⁴	9 19.00 [He] 2s ² 2p ³	10 20.18 (He) 2s ² 3p ⁵
2	Lithium	Be		Boiling po	int [°C]	- 2140 11 - 5030 * 1.5	5 [g/	1] (0° C, 101	13mbar)					Boron	Carbon	Nitrogen	Oxygen	Fluorine	Ne
	181 0.53 1330 1.0	1277 1.85 2970 1.5				Radioacti	ive	cuonegauv	ity					(2030) 2.35 2550 2.0	(3550) 2.2 4830 2.5	-210 1.25 -196 3.0	-219 1.43 -183 3.5	-220 1.7 -188 4.0	-249 0.9 -246 —
	11 22.99 [Ne] 35 1	12 24.31 [Ne] 3s ² 2												13 26.98 [Ne] 3s ² 3p 3	14 28.09 [Ne] 3s ² 3p ² 4,-4	15 30.97 [Ne] 3s ² 3p ³ 5, 3, -3	16 32.06 [Ne] 3s ² 3p ⁴ 6.4.22	17 35.45 [Ne] 3s ² 3p ⁵ 7.5.3, 1, -1	18 39.95 [Ne] 3s ² 3p ⁶
3	Na Sodium	Magnesium	3	4	5	6	7	8	9		10	11	12	Al Aluminum	Silicon	P Phosphorus	Sulfur	Chlorine	Ar Argon
	892 0.9	1107 1.2	3A	4A	5A	6A	7A	8	8	_	3	1B	2B	2450 1.5	2680 1.8	280 2.1	445 2.5	-35 3.0	-183 —
	19 39.10 [Ar] 4s	20 40.08 [Ar] 4s ² 2	21 44.96 [Ar] 3d 4s ² 3	22 47.88 [Ar] 3d ² 4s ² 4.3	23 50.94 [Ar] 3d ³ 4s ² 5.4.3.2.0	24 52.00 [Ar] 3d ⁵ 44 6.3.2.0	25 54.94 [Ar] 3d ⁵ 4s ² 7.6.4.3.2.01	26 55.85 [Ar] 3d ⁶ 4s ² 6.3.2.02	27 58.93 [Ar] 3d ³ 4s ² 3, 2, 0, -1	4	8 58.70 [Ar] 3d ⁶ 4s ² 3.2.0	29 63.55 [Ar] 3d ¹⁰ 4s 2.1	30 65.38 [Arl 3d ¹⁰ 4s ² 2	31 69.72 [Ar] 3d ¹⁰ 4s ² 4p	32 72.59 [Ar] 3d ¹⁰ 4s ² 4p ² 4	33 74.91 (Ar) 3d ³⁰ 4s ² 4p ³ 5.33	34 74.91 [Ar] 3d ¹⁰ 4e ² 4p ⁴ 6.4.2	35 79.90 [Ar] 3d ¹⁰ 4s ² 4p ⁴ 7.5.3.11	36 83.80 (Ar) 3d ¹⁰ 4s ² 4p ⁶
4	K Potassium	Calcium	Sc Scandium	Ti	V Varadium	Chromium	Mn Manganese	Fe	Co		Ni	Cu	Zn	Gattium	Germanium	As	Selenium	Bromine	Krypton
	760 0.8	1440 1.0	2730 1.3	3260 1.5	3450 1.5	2200 1.6	2097 1.5	3000 1.8	2900 1.9		453 8.9 730 1.9	1453 8.9 2730 1.9	420 7.13 906 1.6	2237 1.6	937 5.32 2830 1.8	- 2.0	685 2.4	58 2.8	-157 3.7
	37 85.47 [Kr] 5s	38 87.62 [Kr] 5s ²	39 88.91 [Kr] 4d 5x ²	40 91.22 [Kr] 4d ² 5s ²	41 91.22 [Kr] 4d ⁴ 5s	42 95.94 [Kr] 4d ³ 5s 6 5 4 3 2 0	43 (98.91) [Kr] 4d ⁵ 5s ²	44 101.07 [Kr] 4d ⁷ 5s	45 102.91 [Kr] 4d ⁸ 5s	4	6 106.42 [Kr] 4d ¹⁰	47 107.87 (Kr) 4d ¹⁰ 5s	48 112.41 [Kr] 4d ¹⁰ 5s ²	49 114.82 [Kr] 4d ⁹⁰ 5s ² 5p	50 118.69 [Kr] 4d ¹⁰ 5s ² 5p ²	51 121.75 (Kr) 44 ³⁰ 5s ² 5p ³	52 127.60 [Kr] 3d ¹⁰ 5s ² 5p ⁴	53 126.90 [Kr] 44 ⁰⁰ 5x ² 5p ³	54 131.29 [Kr] 4d ¹⁰ 5s ² 5p ⁶
5	Rb Rebidium	Strontium	Yurium	Zr	Niobium	Mo	Tc	Ru	Rh		Pd	Ag	Cd	In	Sn Tin	Sb	Te	I Iodine	Xe
	39 1.53 688 0.8	768 2.6 1380 1.0	1509 4,47 2927 1.2	1852 6.49 3580 1.4	2468 8.57 4927 1.6	2610 10.2 5560 1.8	2140 11.5 5030 = 1.9	2500 12.4 3900 2.2	1966 12.4 3730 2.2	1.00	552 12.0 140 2.2	961 10.5 2210 1.9	321 8.65 765 1.7	156 7.31 2080 1.7	232 7.30 2270 1.8	631 6.69 1380 1.9	450 6.24 990 2.1	114 4.94 183 2.5	-112 5.89
2	55 132.91 [Xe] 6s	50 137.33 [Xe] 6s ² 2	[Xe] 4f ¹⁴ 5d 6s ² 3	[Xe] 48 ¹⁴ 5d ² 6s ² 4	73 180.95 [Xe] 41 ⁶⁴ 5d ³ 6s ² 5	74 185.85 [Xe] 4f ⁴⁴ 5d ⁴ 6s ² 6, 5, 4, 3, 2, 0	75 186.21 [Xe] 4f ¹⁴ 5d ³ 6s ² 7, 6, 4, 2, -1	76 190.20 [Xe] 4f ¹⁴ 5d ⁶ 6s ² 8, 6, 4, 3, 2, 0, -2	[Xe] 4t ¹⁴ 5d ⁷ 6s ² 6, 4, 3, 2, 1, 0, -1	p	8 195.08 (c) 4f ¹⁴ 5d ⁹ 6s ²	79 196.97 [Xe] 4t ¹⁴ 5d ¹⁰ 6s	80 200.59 [Xe] 4t ⁶⁴ 5d ¹⁰ 6s ²	81 204.38 [Xe] 41 ⁶⁴ 5d ¹⁰ 6e ² 6	82 207.20 (Xe) 41 ⁴⁵ 50 ¹⁰ 6s ² 6y	83 208.98 (Xe) 41 ¹⁴ 50 ¹⁰ 6x ² 6p	84 (209) (Xe) 4 ¹⁴ 5d ¹⁰ 6x ² 6y ⁴ 6.4.2	85 (210) (Xe) 4 ¹⁴ 5d ¹⁰ 6e ² 6g ³	86 (222) (Xe) 4 ⁶⁴ 5d ¹⁰ 6e ² 6g ⁶
6	Cs Cesium	Ba Barium	Lu Lutetium	Hf Hafnium	Ta Tantalum	W Tungsten	Re Rhenium	Os Osmium	Ir tridium	-	Platinum	Au	Hg Mercury	Tl	Pb	Bi	Polonium	At	Rn Radon
	690 0.7	1640 0.9	3327 1.2	5400 1.3	5425 1.5	5930 1.7	5900 1.9	5500 2.2	4500 2.2		769 21.4 830 2.2	1063 19.3 2970 2.4	-38 13.6 357 1.9	303 11.85 1457 1.8	327 11.4 1725 1.9	271 9.8 1560 1.9	254 9.3 962 2.0	(302) — 337 2.2	(-71) 9.73
	87 (223.0) [Rn] 7s 1	88 226.03 [Rn] 7s ² 1	103 (262.1) [Rn] 5f ¹⁴ 6d 7s ² 3	104 (261.1) [Rn] 5f ¹⁴ 6d ² 7s ²	105 (262.1) [Rn] 5f ¹⁴ 6d ³ 7s ²	106 (263.1) [Rn] 5f ¹⁴ 6d ⁴ 7s ²	107 (264.1) [Rn] 51 ⁵⁴ 6d ⁵ 7s ²	108 (265.1) [Rn] 5f ¹⁴ 6d ⁶ 7s ²	109 (268) [Rn] 5f ¹⁴ 6d ⁷ 7s ²	1	10 (269) tal 51 ¹⁴ 6d ⁸ 7s ²	111 (272) [Rn] 5f ¹⁴ 6d ¹⁰ 7s ²	112 (277)		114 (289)		116 (289)		118 (293)
7	Fr	Ra Radium	Lr Lawrencium	Rf Rutherfordium	Db Dubnium	Scaborgium	Bohrium	Hassiam	Mt Meitnerium		Uun	Uuu	Uub		Uuq		Uuh		Uuo
	677 • 0.7	1140 + 0.9			Ξ.Ξ	2.2	2.2	- • -	- • -	-		Z • Z	- . -		Ξ.Ξ]	Ξ.Ξ		Ξ • Ξ
			57 13 [Xel 5d	8.91 58 140 6s ² [Xe] 4f 5	0.12 59 140	0.91 60 14 6s ² [Xe] 4f ⁴	4.24 61 (6s ² [Xe] 4f ⁴	145) 62 15 6s ² (Xe) 4f	0.36	63 15	1.96 64	157.25 65	158.93 66	162.50 67	164.93 68 4f ¹¹ 6s ² (Xe)	167.26 69	168.93 70	73.04	
6	Lanthan	oids	La	i Če	Pr	Nd	l Pn	n Sn	n	Eu	0	d 1	Cb I	by 1	io l	Br]	m Y	2 b	
			920 3470	6.17 795 1.1 3468	6.67 935 1.1 3127	6.77 1024 1.1 3027	7.00 (1027) 1.2 2460 *	7.22 1072 - 1790	7.54 1.2	Europi 828 1439	m Gade 5.26 1312 - 3000	7.89 1356 1.1 2800	8.27 Dysp 8.27 1407 1.2 2600	8.54 Ho - 2600	8.80 1497 1.2 2900	9.05 1545 1.2 1727	9.33 824 1.2 1196	6.98 1.1	
7	Actinoid	10	89 () [Rn] 6d	227) 90 23. 7s ² [Rn] 6d ²	2.04 91 23 7s ² [Rn] 5f ² 6	1.04 92 233 d7x ² [Rn] 5t ³ 6	8.03 93 (237 d 7x ² [Rn] 51 ⁴	7.05) 94 (6d.7x ² (Rn) 50	244) ⁶ 7s ²	95 ([Rn] 5f	243) 96 7s ² [Rn] 5	(247) 97 (⁷ 6d 7s ² [Rn]	(247) 98 5f ⁹ 7s ² [Rn]	(251) 99 5f ¹⁰ 7s ² (Rn)	(254) 100 Sf ¹¹ 7s ² [Rn]	(257) 101 Sf ¹² 7s ² [Rn]	(258) 102 5f ¹³ 7s ² (Ra) 5	(259) 1 ¹⁴ 7s ²	
'	Actinoit	10	Actini	Th Thoris	m Protactin	ium Uraniu	m Niptun	Plutoni	lam	Am		m I	Sk Culle	Cf	BS F	m N	1d N	lo	
			1050	10.1 1750 1.1 3850 •	11.7 (1230) 1.3 - *	15.4 1132 1 1.4 3818 + 1	9.07 637 1.4 3900 *	19.5 640 1.3 3235 *	19.81	994	13.7 (1340) 13.51 -		. = =					

"Light blue" elements are metals, "Grey elements" are nonmetals, "Dark blue" elements are kind of in between, clearly Si and Ge are non-metals, Sn is also a semiconductor below ~ 13 °C 33

SECONDARY BONDING

Arises from interaction between dipoles

• Fluctuating dipoles



• Permanent dipoles-molecule induced





Secondary bonds are formed as a result of polarization of molecules or groups of atoms. In water, electrons in the oxygen tend to concentrate away from the hydrogen. The resulting charge difference permits the molecule to be weakly bonded to other water molecules. These hydrogen bonds are crucial to many physical and chemical properties of H_2O





(a) In polyvinyl chloride (PVC), the chlorine atoms attached to the polymer chain have a negative charge and the hydrogen atoms are positively charged. The chains are weakly bonded by van der Waals bonds. This additional bonding makes PVC stiffer,

(b) When a force is applied to the polymer, the week van der Waals bonds are broken and the chains slide easily past one another

Binding Energy, Interatomic Spacing, & Physical Properties

- Interatomic spacing is equilibrium spacing between the centers of two atoms (at a particular temperature), equilibrium is lowest energy state, attractive and repulsive forces are balanced
- Binding (bond) energy is energy required to separate two atoms from their equilibrium spacing to an infinite distance apart, E = mc², so each time two atoms bound to each other, some mass is converted into energy, ...
- Modulus of elasticity, Young's modulus, is slope of the stressstrain curve in elastic region (macroscopic), can be derived from slope of force versus distance curve at interatomic spacing (microscopic)
- Coefficient of thermal expansion and melting temperature can also be explained from binding energy curve



Atoms or ions are separated by equilibrium spacing that corresponds to the minimum interatomic energy for a pair of atoms or ions (or when zero force is acting to repel or attract the atoms or ions, force balance)

If there is external influences, e.g. load, temperature change, equilibrium spacing will change



Fig. 1.3: (a) Force vs interatomic separation and (b) Potential energy vs interatomic separation.

PROPERTIES FROM BONDING: E



force-distance curve F=F(r) for two materials, showing the relationship between atomic bonding and the modulus of elasticity (Young's modulus), a steep slope at equilibrium position x_0 (or r_0) gives a high modulus





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PROPERTIES FROM BONDING: α



Fig. 1.17 (a) The ball-and-spring model of solids in which the springs represent the interatomic bonds. Each ball (atom) is linked to its neighbors by springs. Atomic vibrations in a solid involve 3 dimensions. (b) An atom vibrating about its equilibrium position stretches and compresses its springs to the neighbors and has both kinetic and potential energy.

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Fig. 1.18: The potential energy *PE* curve has a minimum when the atoms in the solid attain the interatomic separation at $r = r_0$. Due to thermal energy, the atoms will be vibrating and will have vibrational kinetic energy. At $T = T_1$, the atoms will be vibrating in such a way that the bond will be stretched and compressed by an amount corresponding to the *KE* of the atoms. A pair of atoms will be vibrating between *B* and *C*. Their average separation will be at *A* and greater than r_0 .

Deeper potential energy wells, which one has for more heavily bond atoms, tend to be more symmetric, coefficient of thermal expansion is, therefore, smaller as equilibrium position does not change so much with temperature

WARNING: only

over a limited temperature range will there be linear relationship

$$\frac{\Delta x}{x_0} = \boldsymbol{a}(T - T_0)$$
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Fig. 1.19: Vibrations of atoms in the solid. We consider, for simplicity a pair of atoms. Total energy is E = PE + KE and this is constant for a pair of vibrating atoms executing simple harmonic motion. At *B* and *C*, *KE* is zero (atoms are stationary and about to reverse direction of oscillation) and *PE* is maximum.

PROPERTIES FROM BONDING: T_M

• Bond length, r



• Bond energy, E₀



Melting Temperature, Tm Energy (r) ro smaller Tm larger Tm

Tm is larger if Eo is larger.

SUMMARY: BONDING

Туре	Bond Energy	Comments
Ionic	Large!	Nondirectional (ceramics)
Covalent	Variable large-Diamond small-Bismuth	Directional (semiconductors, ceramics polymer chains)
Metallic	Variable large-Tungsten small-Mercury	Nondirectional (metals)
Secondary	smallest	Directional inter-chain (polymer) inter-molecular

Material classes and atomic bonds Large bond energy Ceramics, large Tm (lonic & covalent bonding): large E small α Variable bond energy Semiconductors Large to moderate Tm (covalent bonding) large to moderate E Small to moderate α

Metals (Metallic bonding):



Variable bond energy moderate Tm

moderate E moderate α

Highly anisotropic Properties Secondary bonding dominates small T small E large α 47



Figure 2-24 Tetrahedron representing the relative contribution of different bond types to the four fundamental categories of engineering materials (the three structural types plus semiconductors).



MULTITALENTED Pauling, photographed in about 1960, teaches with molecular models. In the foreground is a model of the α -helix structure he proposed for proteins, another of his great achievements. Perhaps Portland (Oregon)'s most famous son, what do you think ?

He got both a Nobel prize for chemistry and a Nobel prize for peace !

(and studied at OSU in Corvallis)